TECHNICAL DATA DATA SHEET 4142, Rev A

SILICON SCHOTTKY RECTIFIER DIE Ultra Low Forward Voltage Drop Typical Voltage Drop 0.30V

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra Low Forward Voltage Drop
- Soft Reverse Recovery at Low and High Temperature
- Low Power Loss, High Efficiency
- Very High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

Maximum Ratings⁽¹⁾:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	20	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form	120	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 msec, sine pulse	1650	Α
Non-Repetitive Avalanche Energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3.7 \text{A}$ L = 6.5 mH	44.5	mJ
Repetitive Avalanche Current	I _{AR}	I_{AS} decay linearly to 0 in 1 μ s f limited by T_J max V_A =1.5 V_R	3.7	А
Max. Junction Temperature	T_J	-	-55 to + 150	°C
Max. Storage Temperature	T_{stg}	-	-55 to + 150	°C

Electrical Characteristics(1):

Characteristics	Symbol	Condition	Тур.	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 120A, Pulse, T _J = 25 °C	0.42	0.48	V
	V_{F2}	@ 120A, Pulse, T _J = 125 °C	0.30	0.35	V
	V_{F3}	@ 120A, Pulse, T _J = 150 °C	0.27	0.32	V
	I _{R1}	@V _R = 30V, Pulse,	2.7	20.0	mA
		T _J = 25 °C			
Max. Reverse Current	I _{R2}	@V _R = 30V, Pulse,	2240	3000	mA
		T _J = 125 °C			
	I _{R3}	@V _R = 5V, Pulse,	100	180	mA
		T _J = 100 °C			
Max. Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C$	6684	8100	pF
		$f_{SIG} = 1MHz,$			
		$I_{SIG} = 50 \text{mV (p-p)}$			

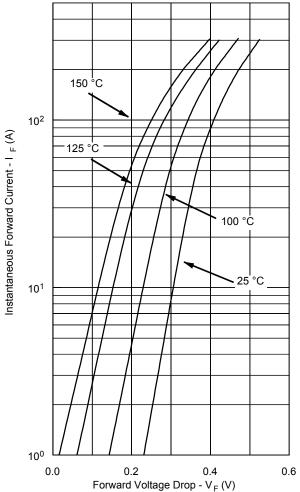
(1) in SHD package

^{• 221} West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798 •

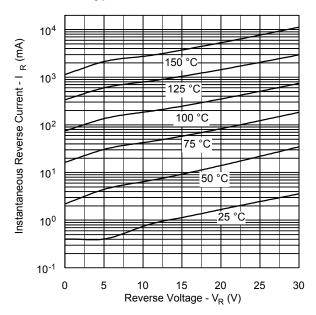
[•] World Wide Web Site - http://www.sensitron.com • E-Mail Address - sales@sensitron.com •

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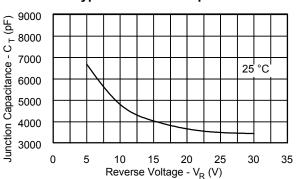
Typical Forward Characteristics



Typical Reverse Characteristics

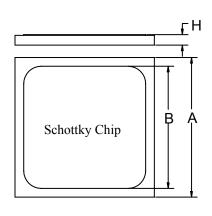


Typical Junction Capacitance



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Mechanical Dimensions: In Inches / mm



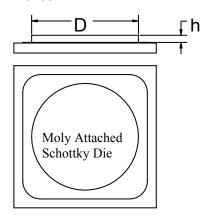


Figure 1

Figure 2

Top side(Anode) metallization:

A = A1 - 25 kÅ minimum, Figure 1

B = Ag - 30 kÅ minimum, Figure 1

C = Au - 12 kÅ min, Figure 2

Bottom side (Cathode) metallization: A, B, C = Ti/Ni/Ag - 30 kÅ minimum.

A	В	D	Н	h
0.275±0.003	0.267 ± 0.003	0.220 ± 0.005	0.0155±0.001	0.011±0.002

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